

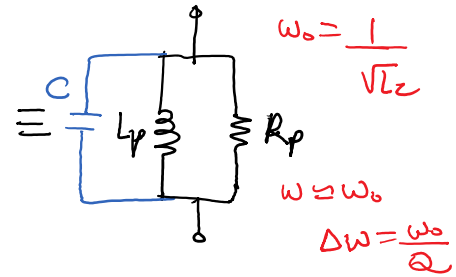
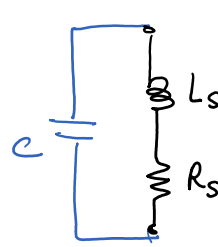
ECE 513 - Lecture 17

Tuesday, October 16, 2018 9:32 AM

$$R_p = R_s (Q^2 + 1)$$

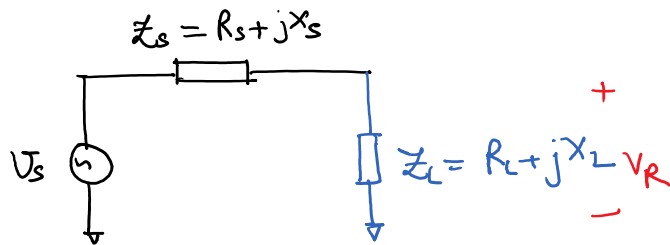
$$X_p = X_s \left(\frac{Q^2 + 1}{Q^2} \right)$$

just or $\frac{1}{j\omega C}$



$$Q = \frac{R_p}{\omega_0 L_p} = \frac{\omega_0 L_s}{R_s}$$

$$Q = \omega_0 R_p C_p = \frac{1}{\omega_0 R_s C_s}$$



Power delivered to the load

V_R & V_S are the rms voltages across the load & the source

$$\frac{|V_R|^2}{R_L} = \frac{R_L |V_S|^2}{(R_S + R_L)^2 + (X_S + X_L)^2}$$

Maximize

$(X_S + X_L) \leftarrow 0 \Rightarrow X_S = -X_L$

$$\frac{\partial}{\partial R_S} \left[\frac{R_L}{(R_S + R_L)^2} \right] = 0$$

$$R_S = R_L$$

$$Z_L = R_L + jX_L = R_S - jX_S$$

$$Z_L = Z_S^* \quad \text{or} \quad Z_S = Z_L^*$$

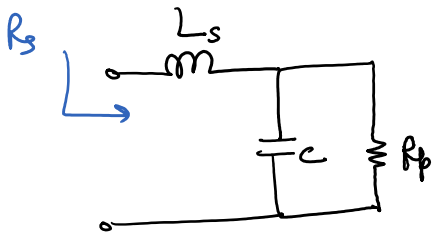
Maximum Power Transfer.

L-match:

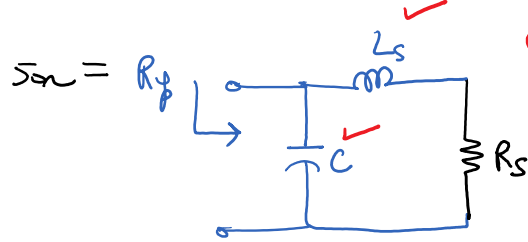
$$R_p = R_s (Q^2 + 1)$$

$$= 10 R_s \text{ for } Q=3$$

$$L_p = L_s \left(\frac{Q^2}{Q^2 + 1} \right)$$

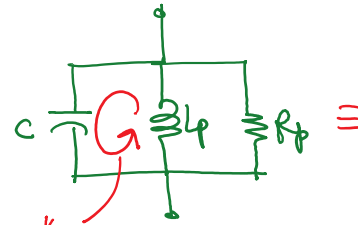


for $Q=3$



Upward impedance Transformation
 $= S\tilde{r}$

\equiv



\equiv R_p
 @ $\omega = \omega_0$

Let "resonate" each other

$$j\omega_0 C - \frac{j}{\omega_0 L_p} = 0$$

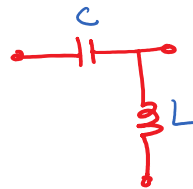
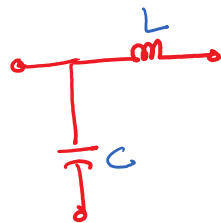
$$R_s = \frac{R_p}{Q^2 + 1}$$

$$R_p = R_s (Q^2 + 1) \longrightarrow \text{for large } Q, \quad Q = \sqrt{\frac{R_p}{R_s}}$$

$$X_p \leq X_s$$

$$Z_0 = \sqrt{L/C}$$

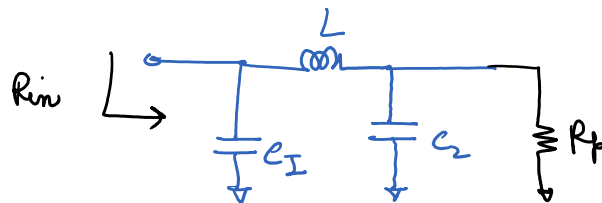
$$R_p R_s \leq \frac{L_s}{C} = Z_0^2$$



2-degrees of freedom

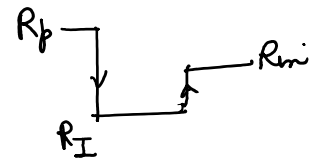
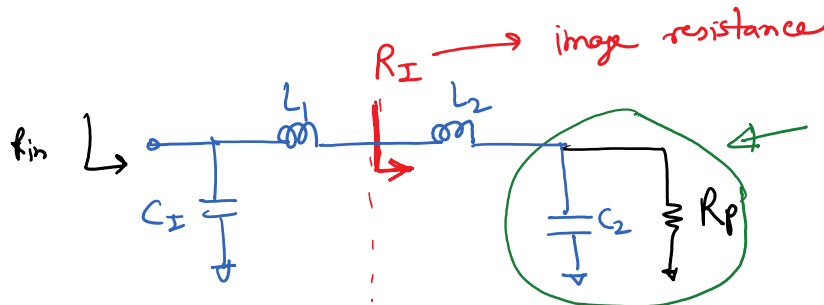
π - Match :

- * L-match limitations \Rightarrow we can specify only 2 of the three specifications : ω_0 , $\frac{R_p}{R_s}$ or Q
- * To get a 3rd degree of freedom, we use a π network

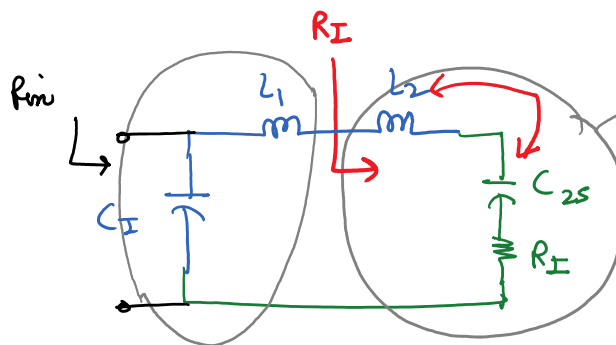


$$Q = \sqrt{\frac{R_p}{R_s}}$$

$\Rightarrow \pi$ -Match \Rightarrow Cascade of two L-matches



Three degrees of freedom $\rightarrow C_2, C_1 \text{ \& } L = (L_1 + L_2)$



* Q of the right hand l-section

$$Q_{\text{right}} = \frac{\omega_0 L_2}{R_I} = \sqrt{\frac{R_p}{R_I} - 1} \quad \text{--- (1)}$$

* The left-hand l-section sees a resistance R_I at resonance

$$Q_{\text{left}} = \frac{\omega_0 L_1}{R_I} = \sqrt{\frac{R_{in}}{R_I} - 1} \quad \text{--- (2)}$$

* Overall Q of the network

$$Q = \frac{\omega_0 (L_1 + L_2)}{R} = \sqrt{\frac{R_{in}}{R_I} - 1} + \sqrt{\frac{R_p}{R_I} - 1} \quad \text{--- (3)}$$

$$Q = \frac{\omega_0 (L_1 + L_2)}{R} = \sqrt{\frac{R_{in}}{R_I} - 1} + \sqrt{\frac{R_p}{R_I} - 1} \longrightarrow \textcircled{3}$$

* we compute R_I from $\Sigma^n \textcircled{3}$ and then we have

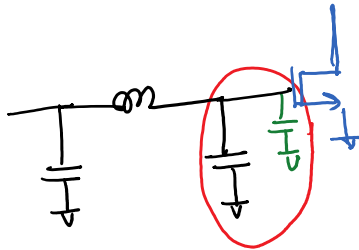
$$L_1 + L_2 = \frac{Q R_I}{\omega_0}$$

$$C_1 = \frac{Q_{right}}{\omega_0 R_{in}}$$

$$C_2 = \frac{Q_{right}}{\omega_0 R_p}$$

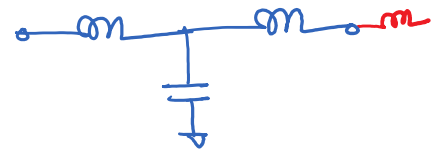
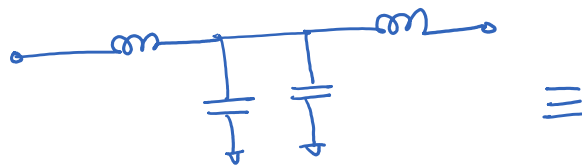
$\Sigma^n \textcircled{3}$ requires iteration \Rightarrow To simplify it we can assume that Q is large \Rightarrow Then R_I is approximated as

$$R_I \approx \frac{(\sqrt{R_{in}} + \sqrt{R_p})^2}{Q^2} \longrightarrow \text{instead of } \Sigma^n \textcircled{3} \text{ for } Q \gg 1$$



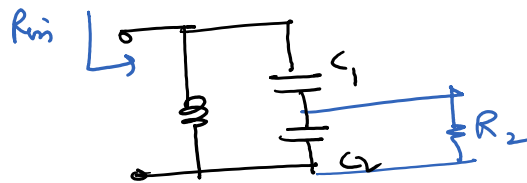
parasitic capacitance can be absorbed in the network design.

T-Match:



"See uploaded chapter"

Tapped Capacitor or Inductor



Transmission Line Match:

$$R_2 = \frac{R_L}{Q^2 + 1}$$

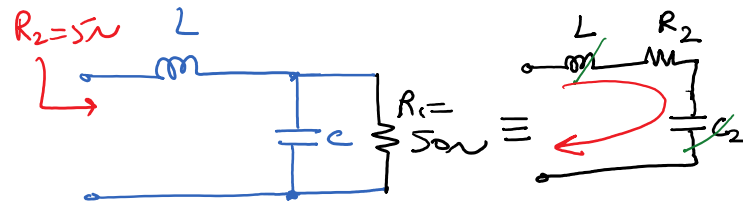
Ex:

$$f = 1 \text{ GHz}$$

$$R_1 = 5 \Omega \rightarrow R_2 = 5 \Omega$$

$$BW = 25 \text{ MHz}$$

$$Q = \sqrt{\frac{R_L}{R_1} - 1} = \sqrt{10 - 1} = 3$$



But we desire $BW = 25 \text{ MHz} \Rightarrow Q = \frac{f_0}{BW} = \frac{10^9}{25 \times 10^6} = 40$

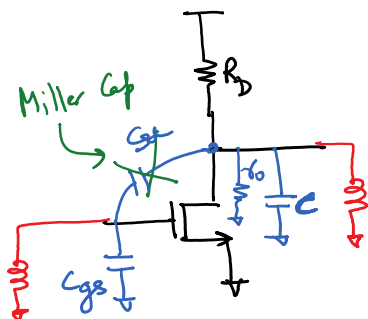
$$Q = \frac{\omega_0 L_s}{R_s} = \frac{\cancel{R_L}}{\cancel{\omega_0 L_p}} = \frac{\omega_0 L}{R_2} \Rightarrow L = \frac{Q R_2}{\omega_0} = 2.39 \text{ nH}$$

$$Q = \omega_0 R_p C_p = \frac{\cancel{1}}{\cancel{\omega_0 R_s C_s}} = \omega_0 R_1 C \rightarrow C = \frac{Q}{\omega_0 R_1} = 9.55 \text{ pF}$$

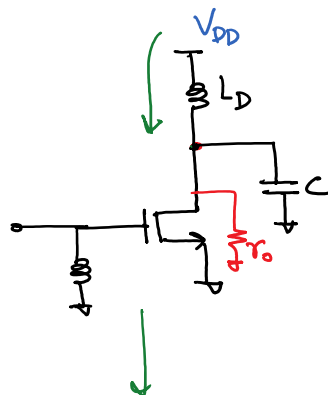
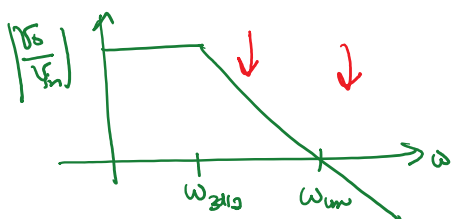
See Π -match example from T.H. Lee's chapter

Tuned Circuit Topologies and Analysis:

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$f \rightarrow f_T$

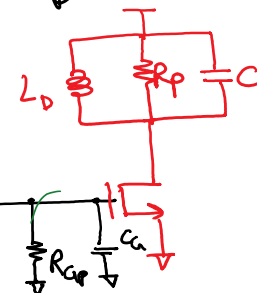


Inductor biases the drain

$$V_{DS} = V_{DD} \text{ biased at } V_{DD}$$

drain can swing above V_{DD} .

Model for analysis

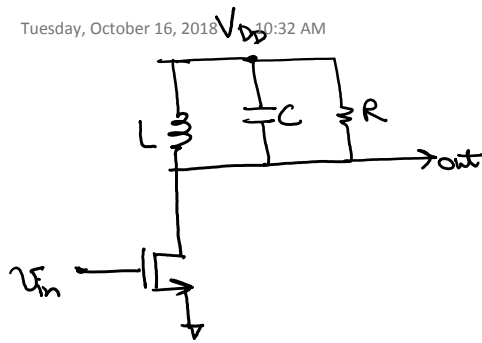


* & general its common to cascade a large number of tuned amplifier stages.

* Tuned amplifiers are used extensively to provide selective amplification and a degree of filtering of unwanted signals.

→ power requirements to obtain narrowband gain are considerably less.

⇒ Single-tank tuned CS amplifier



$R \Rightarrow$ transistor's output impedance

$C \Rightarrow$ transistor's drain parasitics + load

$C_{gd} \Rightarrow$ Ignored

$$A_v(s) = -g_{m,eff} Z_L(s)$$

$$= -\frac{g_{m,eff}}{C} \cdot \frac{s}{s^2 + s\left(\frac{1}{RC}\right) + \frac{1}{LC}}$$

$$\Rightarrow A_v(j\omega_0) = -\frac{g_{m,eff}}{C} \cdot \frac{j\omega_0}{-\frac{1}{LC} + \frac{j\omega_0}{RC} + \frac{1}{LC}}$$

$$= -g_{m,eff} \cdot R$$

$$\omega_0 = \frac{1}{\sqrt{LC}}$$

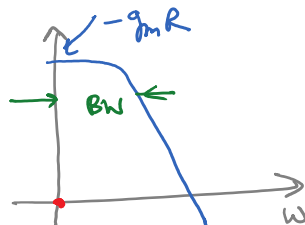
$$Q = \omega_0 RC = \frac{\omega_0 L}{R}$$

$$BW = \frac{1}{RC}$$

$$\boxed{R/\omega_0 L}$$

$$g_{m,eff} \times BW = g_{m,eff} R \cdot \frac{1}{RC}$$

$$= \frac{g_{m,eff}}{C}$$



$$Z_L = sL \parallel R \parallel \frac{1}{sC}$$

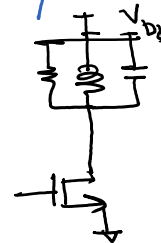
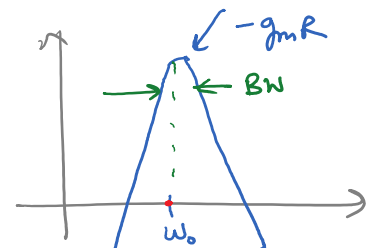
$$\frac{1}{Z_L} = \frac{1}{sL} + \frac{1}{R} + sC$$

$$= \frac{R + sL + s^2 LC}{sLR}$$

$$\Rightarrow Z_L = \frac{1}{C} \cdot \left[\frac{s}{s^2 + s\left(\frac{1}{RC}\right) + \frac{1}{LC}} \right]$$

2^{nd} -order Transfer Fⁿ

$$\omega_0 = \frac{1}{\sqrt{LC}}$$



f_{max} sets the ultimate limit on $\omega_0 = 2\pi f_0$